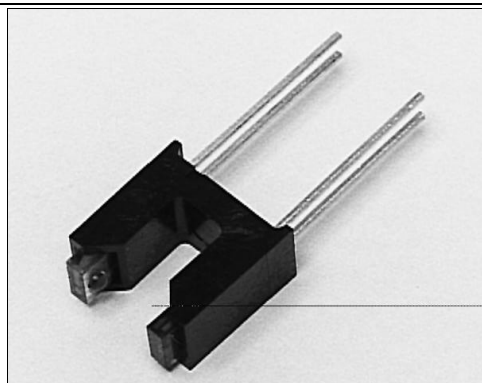


# HOA0825

## Transmissive Sensor

### FEATURES

- Phototransistor output
- Four mounting configurations
- 0.165 in.(4.2 mm) slot width



INFRA-52.TIF

### DESCRIPTION

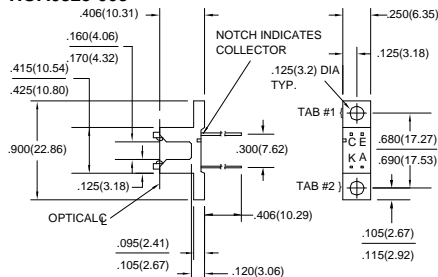
The HOA0825 series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. A slot in the housing between emitter and detector provides the means for mechanically interrupting the emitter beam. The phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA0825 series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

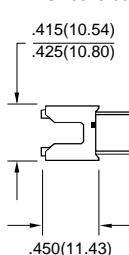
Tolerance 3 plc decimals  $\pm 0.010(0.25)$   
2 plc decimals  $\pm 0.020(0.51)$

#### HOA0825-003



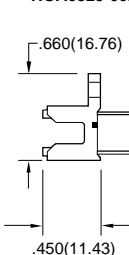
DIM\_040.ds4

#### HOA0825-001

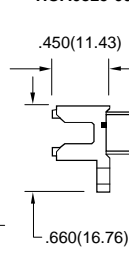


DIM\_40b.ds4

#### HOA0825-002



#### HOA0825-004



# HOA0825

Transmissive Sensor

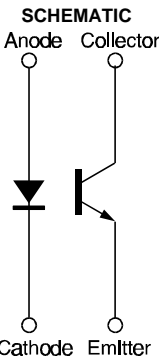
ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
<b>IR EMITTER</b>						
Forward Voltage	$V_F$			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	$I_R$			10	$\mu\text{A}$	$V_R=3\text{ V}$
<b>DETECTOR</b>						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	30			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current	$I_{CEO}$			100	nA	$V_{CE}=10\text{ V}, I_F=0$
<b>COUPLED CHARACTERISTICS</b>						
On-State Collector Current HOA0825-001, -002, -003, -004	$I_{C(ON)}$	0.5			mA	$V_{CE}=0.5\text{ V}$ $I_F=20\text{ mA}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$			0.4	V	$I_F=20\text{ mA}$ $I_C=250\text{ }\mu\text{A}$
Rise And Fall Time	$t_r, t_f$		15		$\mu\text{s}$	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$

**ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)	
Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

<b>IR EMITTER</b>	
Power Dissipation	100 mW <sup>(1)</sup>
Reverse Voltage	3 V
Continuous Forward Current	50 mA

<b>DETECTOR</b>	
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW <sup>(1)</sup>
Collector DC Current	30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

# HOA0825

## Transmissive Sensor

Fig. 1 IRED Forward Bias Characteristics

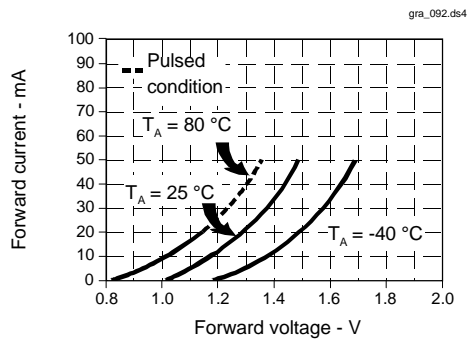


Fig. 2 Non-Saturated Switching Time vs Load Resistance

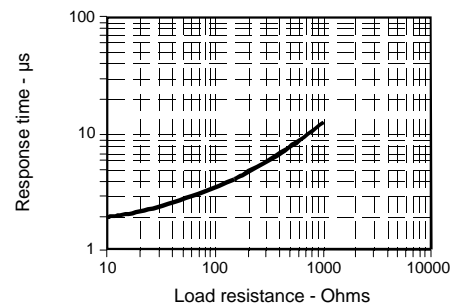


Fig. 3 Dark Current vs Temperature

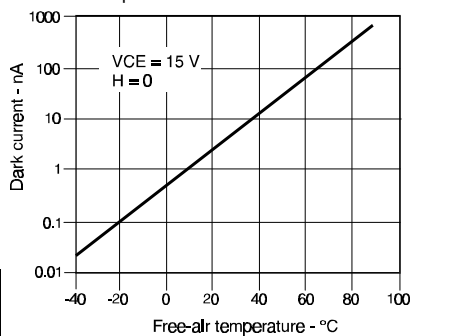
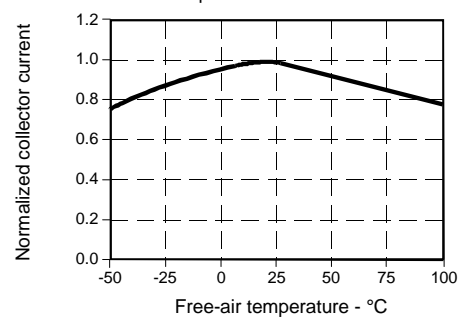


Fig. 4 Collector Current vs Ambient Temperature



All Performance Curves Show Typical Values



# HOA0825

Transmissive Sensor

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